NSN 5961-01-376-4519

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View Online at https://aerobasegroup.com/nsn/5961-01-376-4519

nclosure Material:
Ceramic and metal
Overall Length:
Between 0.795 inches and 0.805 inches
Overall Height:
0.170 inches
Overall Width:
Between 0.720 inches and 0.750 inches
Mounting Facility Quantity:
2
nternal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Unthreaded hole
Features Provided:
Burn in and hermetically sealed case
Cubic Measure:
0.026 cubic inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
40.0 collector to base voltage/static/emitter open and 15.0 collector to emitter voltage/static/base open and 3.5 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
1.10 amperes source cutoff current
Power Rating Per Characteristic:
3.8 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Precious Material And Location:
Terminal and flange plated gold
Precious Material:
Gold
Terminal Type And Quantity:
2 ribbon and 1 case
Shelf Life:
N/a

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Unit Of Measure:

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Demilitarization:

No

Fiig:

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